International Rectifier

50WQ03FN

SCHOTTKY RECTIFIER

5.5 Amp



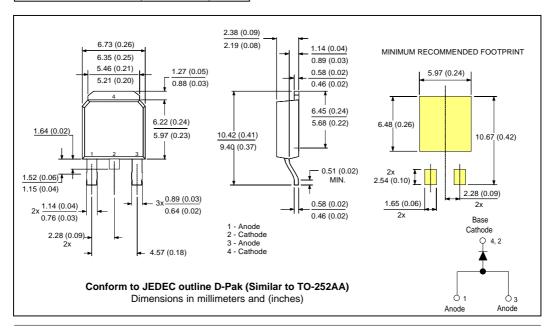
Major Ratings and Characteristics

Characteristics	50WQ03FN	Units
I _{F(AV)} Rectangular waveform	5.5	А
V _{RRM}	30	V
I _{FSM} @ tp=5μssine	320	Α
V _F @ 5 Apk, T _J = 125°C	0.35	V
T _J range	-40 to 150	°C

Description/Features

The 50WQ03FN surface mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, free-wheeling diodes, battery charging, and reverse battery protection.

- Popular D-PAK outline
- Small foot print, surface moutable
- · Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability



Voltage Ratings

Part number	50WQ03FN	
V _R Max. DC Reverse Voltage (V)	00	
V _{RWM} Max. Working Peak Reverse Voltage (V)	30	

Absolute Maximum Ratings

	About Maximum Ratingo					
	Parameters	50WQ	Units	Conditions		
I _{F(AV)}	Max. Average Forward Current	5.5	Α	50% duty cycle @ T _C = 136°C, r	ectangular wave form	
	* See Fig. 5					
I _{FSM}	Max. Peak One Cycle Non-Repetitive	320	Α	5μs Sine or 3μs Rect. pulse	Following any rated load condition and with	
	Surge Current * See Fig. 7	130		10ms Sine or 6ms Rect. pulse	rated V _{RRM} applied	
E _{AS}	Non-Repetitive Avalanche Energy	10	mJ	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 2.0 \text{Amps}, L = 5$	5 mH	
I _{AR}	Repetitive Avalanche Current	2.0	A Current decaying linearly			
				Frequency limited by T_J max. V_J	_A = 1.5 x V _R typical	

Electrical Specifications

	Parameters		50WQ	Units	Conditions	
V _{FM}	Max. Forward Voltage Drop)	0.46	V	@ 5A	T _ 25 °C
	* See Fig. 1 (1)		0.53	V	@ 10A	T _J = 25 °C
			0.35	V	@ 5A	T = 125 °C
			0.46	V	@ 10A	1 _J = 120 0
I _{RM}	Max. Reverse Leakage Cu	rrent	3	mA	T _J = 25 °C	$V_p = \text{rated } V_p$
	* See Fig. 2 (1)		58	mA	T _J = 125 °C	v _R – rated v _R
V _{F(TO}	Threshold Voltage		0.19	V	$T_J = T_J \text{ max.}$	
r _t	Forward Slope Resistance		22.22	mΩ	-	
C _T	Typical Junction Capacitan	се	590	pF	V _R = 5V _{DC} , (test signal range 100Khz to 1Mhz) 25 °C	
L _S	Typical Series Inductance		5.0	nH	Measured lead to lead 5mm from package body	

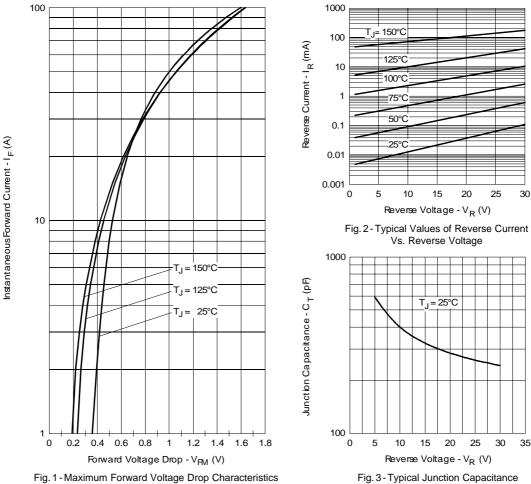
⁽¹⁾ Pulse Width < 300µs, Duty Cycle < 2%

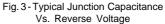
Thermal-Mechanical Specifications

	Parameters	50W	Units	Conditions
T _J	Max. Junction Temperature Range (*)	-40 to 150	°C	
T _{stg}	Max. Storage Temperature Range	-40 to 150	°C	
R _{thJC}	Max. Thermal Resistance Junction to Case	3.0	°C/W	DC operation *See Fig. 4
wt	Approximate Weight	0.3 (0.01)	g (oz.)	
	Case Style	D-PAK		Similar to TO-252AA

 $[\]frac{\text{(*)}}{\text{dTj}} < \frac{\text{dPtot}}{\text{Rth(j-a)}} < \frac{1}{\text{Rth(j-a)}} \quad \text{thermal runaway condition for a diode on its own heatsink}$

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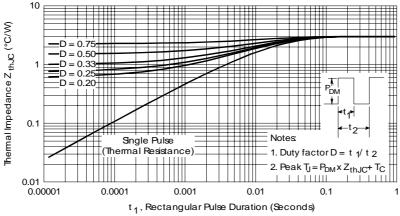


Fig. 4 - Maximum Thermal Impedance $\, Z_{thJC} \,$ Characteristics

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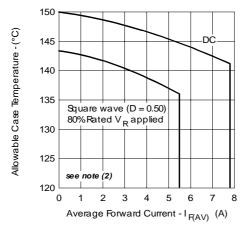


Fig. 5 - Maximum Allowable Case Temperature Vs. Average Forward Current

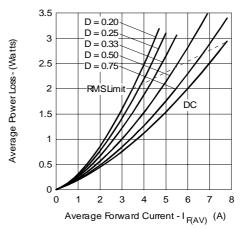


Fig. 6 - Forward Power Loss Characteristics

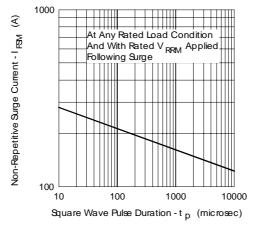
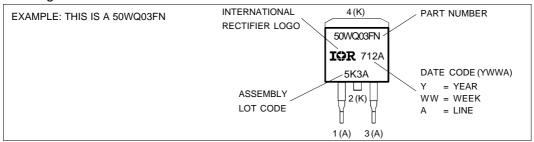


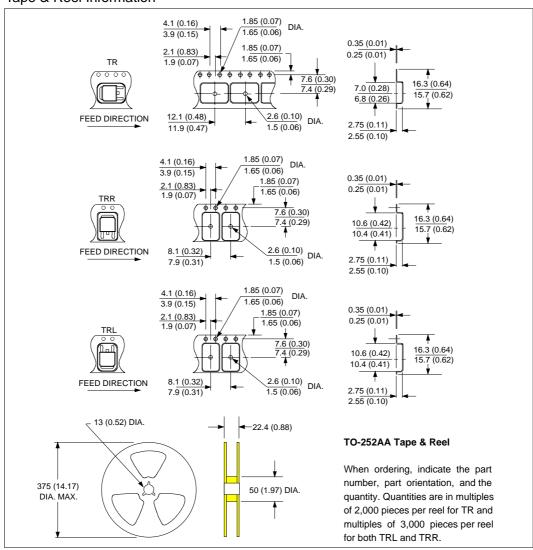
Fig. 7 - Maximum Non-Repetitive Surge Current

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Marking Information



Tape & Reel Information



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Data and specifications subject to change without notice. This product has been designed and qualified for Industrial Level.

Qualification Standards can be found on IR's Web site.



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IR WORLD HEADQUARTERS: 233 Kansas St., El Segundo, California 90245, USA Tel: (310) 252-7105
TAC Fax: (310) 252-7309
Visit us at www.irf.com for sales contact information. 03/03